

USER'S GUIDE

Amplitude Modulators

Models 4101, 4102, 4103 & 4104



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MASTER

Warranty

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Theory and Operation

Introduction

The New Focus 410X series electro-optic amplitude modulators allow you to achieve deep amplitude modulation of your laser beam with a small input voltage, while maintaining large optical apertures. We offer two types of modulators:

- Broadband Amplitude Modulators (AM) for general-purpose applications.
- Resonant Amplitude Modulators (RAM) which are tuned to user-specified frequencies.

Benefits include low drive voltage, high modulation frequency, low insertion loss, good RF shielding, and high power handling capability. Specifications are show in the table on page 11. The 4101 and 4102 modulators are provided in magnesium-oxide-doped lithium niobate for use in the near 0.5-0.9 μm range. The 4103 and 4104 modulators are provided in lithium niobate for use in the 1.0-1.6 μm range. The user is free to define the modulation frequency of the resonant modulators.

Theory

The 410X series amplitude modulators require external polarizers at the input and output. Without the external polarizers, these amplitude modulators are actually voltage-variable waveplates. (Polarizers are not provided with the modulators so that you may

vary the polarizers used according to your specific application.)

When the amplitude modulator is placed between crossed polarizers the output is given by the equation:

$$I_0 = I_i \sin^2 \left(\frac{V_i}{V_\pi} \cdot \frac{\pi}{2} + \phi_0 \right)$$

where I_i is the input intensity, ϕ_0 is any intrinsic or extrinsic state phase bias, V_i is the input drive voltage, and V_π is shown approximately in the specifications table on page 11. The extinction ratio depends on the quality of the polarizers. With high-quality polarizers, extinction ratios of 100:1 are achievable.

When the DC bias is set to $V_\pi/2$ the output intensity is given by:

$$I_0 = I_i \frac{1}{2} \cdot \left[1 + \cos \left(\frac{V_i}{V_\pi} \cdot \pi \right) \right]$$

Performance of the amplitude modulators is defined by insertion loss, modulation depth, and the voltage standing wave ratio (VSWR).

Insertion Loss

Insertion loss is determined by the absorption and scatter in the electro-optic crystal, and by the quality of the anti-reflection coatings on the end faces. Low optical losses are critical in applications of the New Focus amplitude modulators, so great care is taken to ensure insertion loss is minimized.

Modulation Depth

This describes the magnitude of the amplitude modulation imposed on the input laser beam by the modulator. This depth is optimized by New Focus' resonant circuit design which drives the resonant modulator, and by optimizing the alignment of the input beam's polarization with the crystal active axis.

Voltage Standing Wave Ratio (VSWR)

The VSWR describes the level of impedance matching between the driving source and the amplitude modulator, which directly affects the power transfer into the device. Resonant amplitude modulators are designed to be very close to $50\ \Omega$ at resonance. Thus, they will have a greatly enhanced return loss at the specified resonant frequency. All New Focus resonant amplitude modulators are accurately tested for VSWR by looking at return loss vs. frequency around the modulation frequency. These results are provided at the rear of this manual.

Operation

Aligning the module to the optical beam:

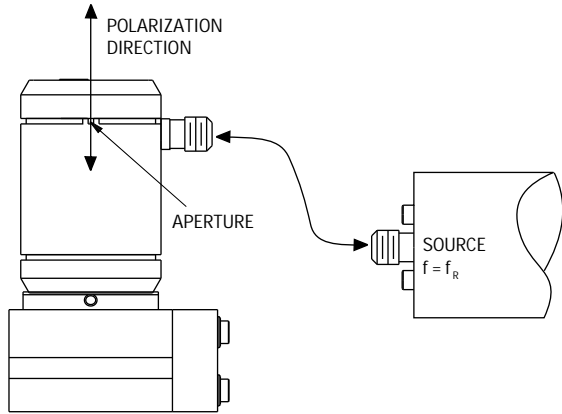
1. Mount the module on an adjustable positioning device using the $1/4$ "-20 tapped hole on the base of the module. We recommend the New Focus Model 9071 tilt aligner because of its tilt and translation capabilities.
2. Turn on the optical beam. Orient the beam so it is vertically polarized on the input aperture. The x- and z-crystal axes are oriented $\pm 45^\circ$ with respect to vertical. Polarizers are not provided with the amplitude modulators.
3. Position and align the module so that the beam passes through the 2-mm input and output apertures, clearing them without clipping. The beam should be collimated with a diameter of less than 2 mm, but such that the Rayleigh range is at least the length of the crystal. A good beam diameter is 200–500 μm . The apertures are made significantly smaller than the crystal cross section to force the optical beam to travel

through a region of the crystal where the applied electric field is very uniform.

Note

Since the optical alignment on any modulator can be disturbed by the output cable, ensure that its SMA orientation is not obstructing the alignment and use a strain relief on the cable.

Figure 1:
A high-frequency resonant modulator driven by a source tuned to f_R . The module is mounted on a Model 9071 tilt aligner.



Setting Up the Input Signal:

Using an SMA cable with a connector, connect the output port on the back of the module to a modulating source appropriate for the type of modulator you are using (resonant or broadband).

Resonant modulators are tuned to a specific frequency and require very low drive voltages, such as that from a simple crystal oscillator or a function generator that has an output impedance near $50\ \Omega$. Resonant modulators have a greatly reduced return loss at the specified frequency compared to broadband modulators.

Broadband modulators require large drive voltages and have a bandwidth dependent on the impedance of the modulating source. With a $50\text{-}\Omega$ source, the bandwidth will be approximately 200 MHz. The source must be able to drive an open circuit without causing damage to the source.

Customer Service

Technical Support

Information and advice about the operation of any New Focus product is available from our applications engineers. For quickest response, ask for “Technical Support” and know the model and serial number for your product.

Hours: 8:00–5:00 PST, Monday through Friday (excluding holidays).

Toll Free: 1-866-NUFOCUS (1-866-683-6287)
(from the USA & Canada only)

Phone: (408) 980-5903

Support is also available by fax and email:

Fax: (408) 987-3178

Email: techsupport@newfocus.com

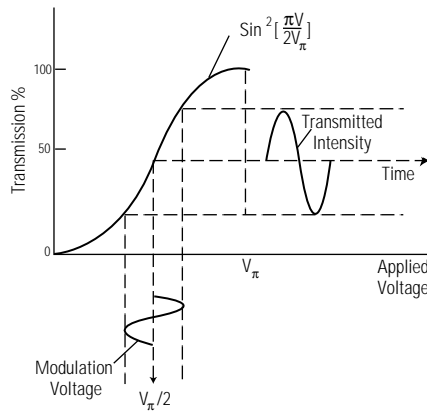
We typically respond to faxes and email within one business day.

Service

In the event that your modulator malfunctions or becomes damaged, please contact New Focus for a return authorization number and instructions on shipping the unit back for evaluation and repair.

Appendix I: Linear Amplitude Modulation

Figure 2:
The transfer function of an amplitude modulator between crossed polarizers is a \sin^2 function.



Linear amplitude modulation can be achieved over a limited range by biasing the amplitude modulator at the quarter-wave point which is equivalent to the 50%-transmission point. This can be achieved either by applying a DC-bias voltage and a small RF signal to the modulator, or by including a quarter waveplate oriented vertical to the modulator housing.

Appendix II: Specifications

	Model 4101	Model 4102
Wavelength Range	0.5-0.9 μm	0.5-0.9 μm
Material	MgO:LiNbO ₃	MgO:LiNbO ₃
Type	Resonant Amplitude Modulation	Broadband Amplitude Modulation
Aperture	2 mm	2 mm
Insertion Loss*	<0.3 dB	<0.3 dB
Max V _{1/4}	19 V @ 633nm	195 V @ 633nm
Operating Frequency	0.01–250 MHz	DC–200 MHz
RF Bandwidth	2–4% freq.	200 MHz
Connector	SMA	SMA
Impedance	50 Ω	10 pF
VSWR	<1.5	-NA-
Max. RF Power	1 W	10 W
Max. Optical Intensity	<2 W/mm ² @ 532 nm	

* Insertion loss is wavelength dependent.

	Model 4103	Model 4104
Wavelength Range	1.0-1.6 μm	1.0-1.6 μm
Material	LiNbO ₃	LiNbO ₃
Type	Resonant Amplitude Modulation	Broadband Amplitude Modulation
Aperture	2 mm	2 mm
Insertion Loss*	<0.3 dB	<0.3 dB
Max V _{1/4}	30 V	300 V
Operating Frequency	0.01–250 MHz	DC–200 MHz
RF Bandwidth	2–4% freq.	200 MHz
Connector	SMA	SMA
Impedance	50 Ω	10 pF
VSWR	<1.5	-NA-
Max. RF Power	1 W	10 W
Max. Optical Intensity	<1.3 W/mm ² @ 1.3 μm	

* Insertion loss is wavelength dependent.

Appendix III: Performance Data

Model Number: _____

Serial Number: _____

Frequency: _____

Wavelength: _____

Input RF Power: _____

Return Loss: _____

VSWR: _____

Q: _____

